Diode Semiconductor Device - Page 1 of 1



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### **Inclosure Material:**

Metal

**Overall Length:** 

1.453 inches

Mounting Facility Quantity:

1

## Mounting Method:

Threaded stud

**Features Provided:** 

Hermetically sealed case

## **Overall Width Across Flats:**

Between 0.667 inches and 0.687 inches

**Thread Size:** 

0.250 inches

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

240.0 nonrepetitive peak reverse voltage, peak total value and

# **Current Rating Per Characteristic:**

35.00 amperes average forward current averaged over a full 60-hz cycle

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Thread Series Designator:**

Unf

Terminal Type And Quantity:

1 threaded stud and 1 tab, solder lug

#### **Specification Data:**

81349-mil-s-19500/297 government specification

Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

Fiig:

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